



**superior** performance.  
**powerful** technology.

# Recent Results in 2G HTS Wire Technology Development at SuperPower

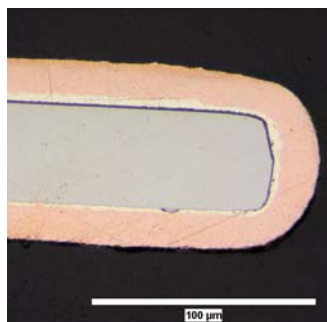
J. Jimenez, Y. Chen, X. Xiong, Y. Xie, X. Zhang, A. Rar, M. Martchevskii, Y. Qiao, A. Knoll, K.P. Lenseth, R.M. Schmidt, J. Herrin, D. Hazelton and V. Selvamanickam

ICMC 2008 - Seoul, Korea - July 21-25, 2008

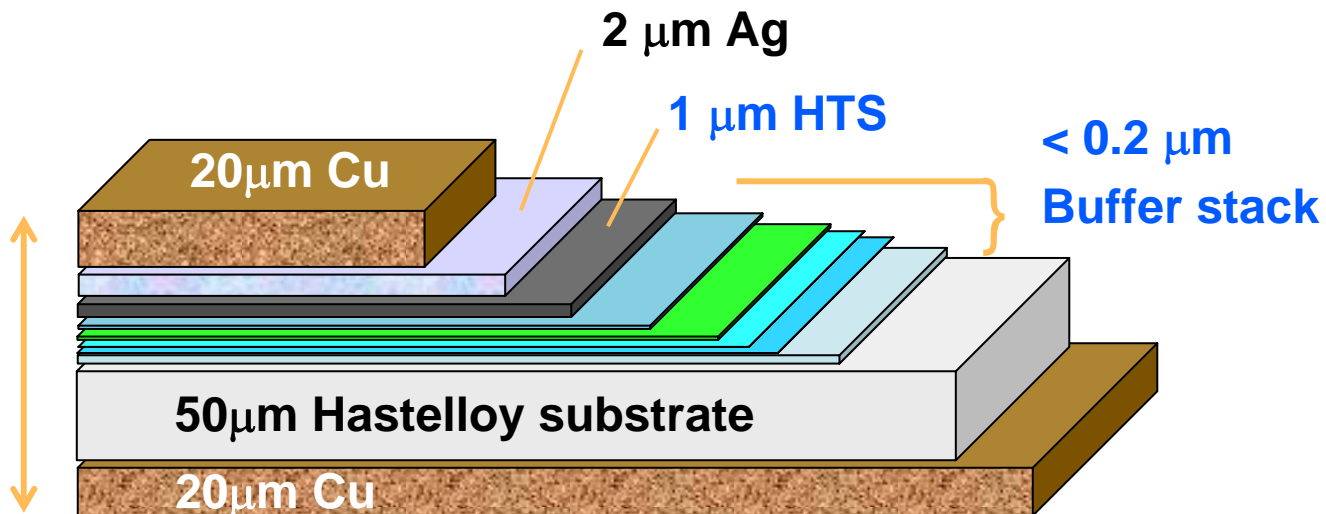
**Program funding from Title III and DOE through UT-Battelle & AFRL. Supported by CRADAs with Oak Ridge, Los Alamos, and Argonne National Laboratories**

# SuperPower 2G HTS wire utilizes high strength substrates coupled with high throughput processing

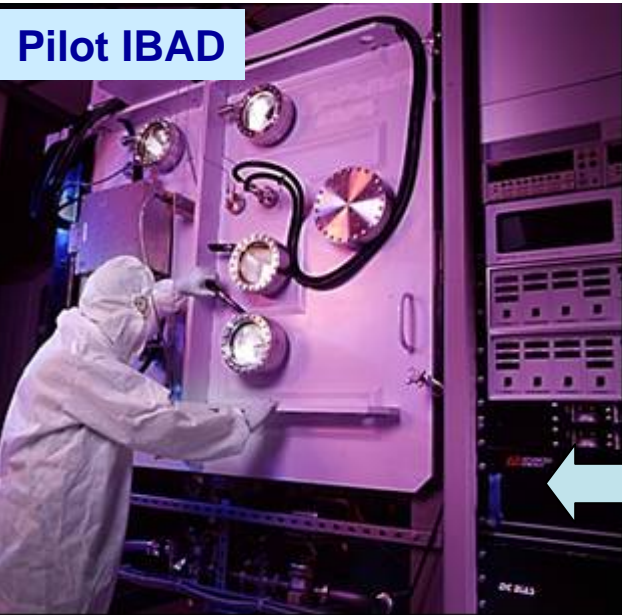
- SuperPower's 2G HTS wire is based on a high throughput thin film manufacturing approach permitting a wide choice of materials combinations
  - Advantages include high strength, low ac loss (non-magnetic, high resistivity substrates) and high engineering current density (ultra-thin substrates)
- High throughput is critical for low-cost 2G wire to enable early commercial adoption
  - IBAD-MgO based buffer technique
  - MOCVD for HTS layer: combination of high deposition rate and large deposition zone



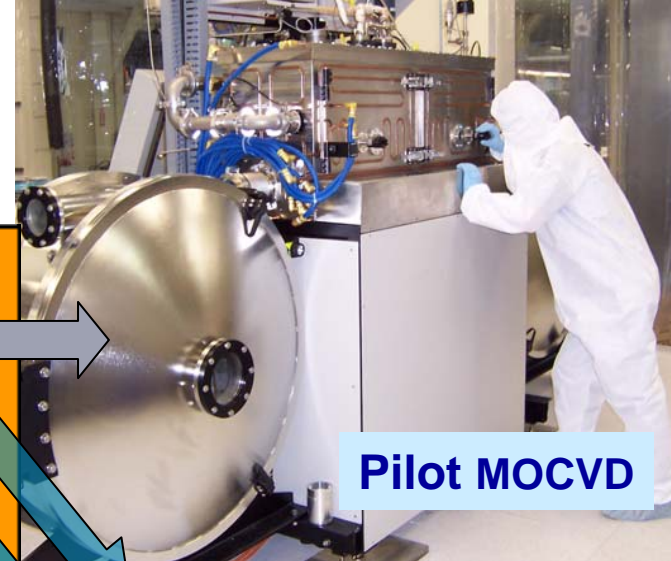
< 0.1 mm



# SuperPower's 2G pilot manufacturing facility has been operational since 2006



**Pilot IBAD**

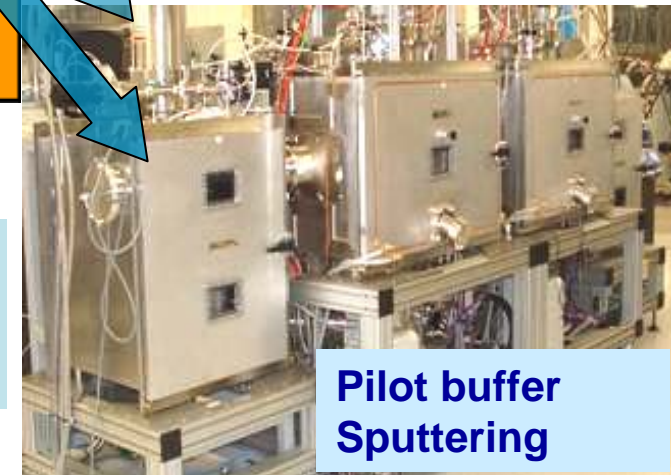


**Pilot MOCVD**

20 $\mu\text{m}$ Cu	
2 $\mu\text{m}$ Ag	
1~ 5 $\mu\text{m}$	HTS
30 nm LMO	
30 nm Homo-epi MgO	
10 nm IBAD MgO	
7 nm Yttria	
80 nm Alumina	
50 $\mu\text{m}$ metal alloy substrate	
20 $\mu\text{m}$ Cu	



**Pilot Substrate Electropolishing**

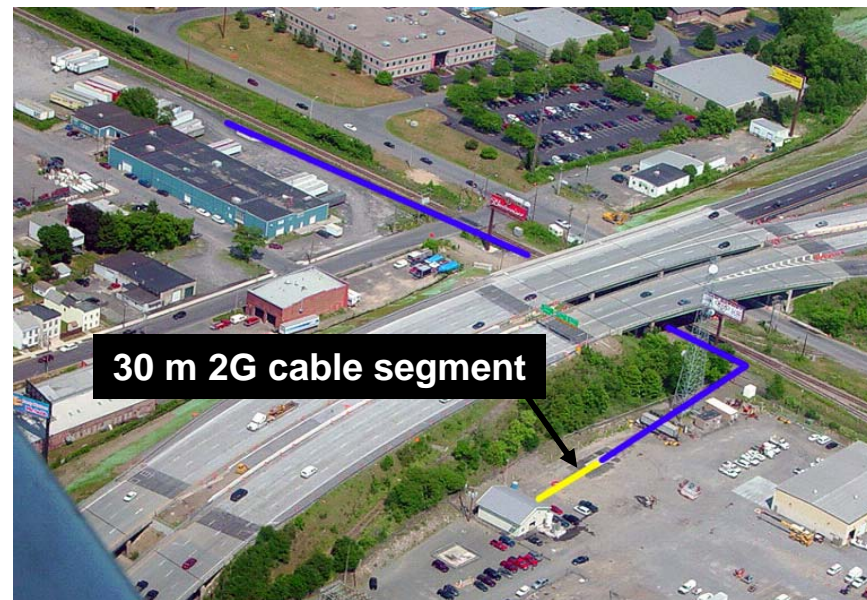


**Pilot buffer Sputtering**

Majority of investment already made for 1000 km/year capability

# SuperPower was the first and is still the only company to demonstrate pilot-scale 2G HTS wire manufacturing

- In Dec. 2006, SuperPower delivered nearly **10 km** of 2G HTS conductor in 2006 to build a 30 m long cable for the Albany Cable project, *which is now the world's first & only 2G device energized in the power grid.*
- *Largest single quantity of 2G delivery*
- 225 segments delivered each with a piece length of 43 m – *not a delivery of tapes from laboratory runs !*

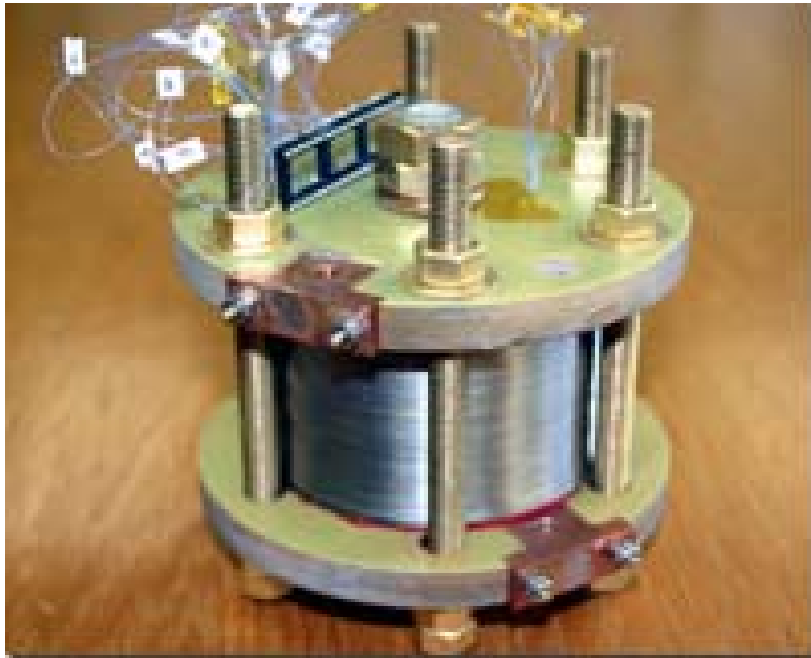


Albany Cable project: National Grid, 350 m long cable. World's first in-grid cable, first underground cable, first cable-to-cable joint.

Excellent demonstration of reproducibility & manufacturing viability of our processes



# World record performance achieved with 2G coil

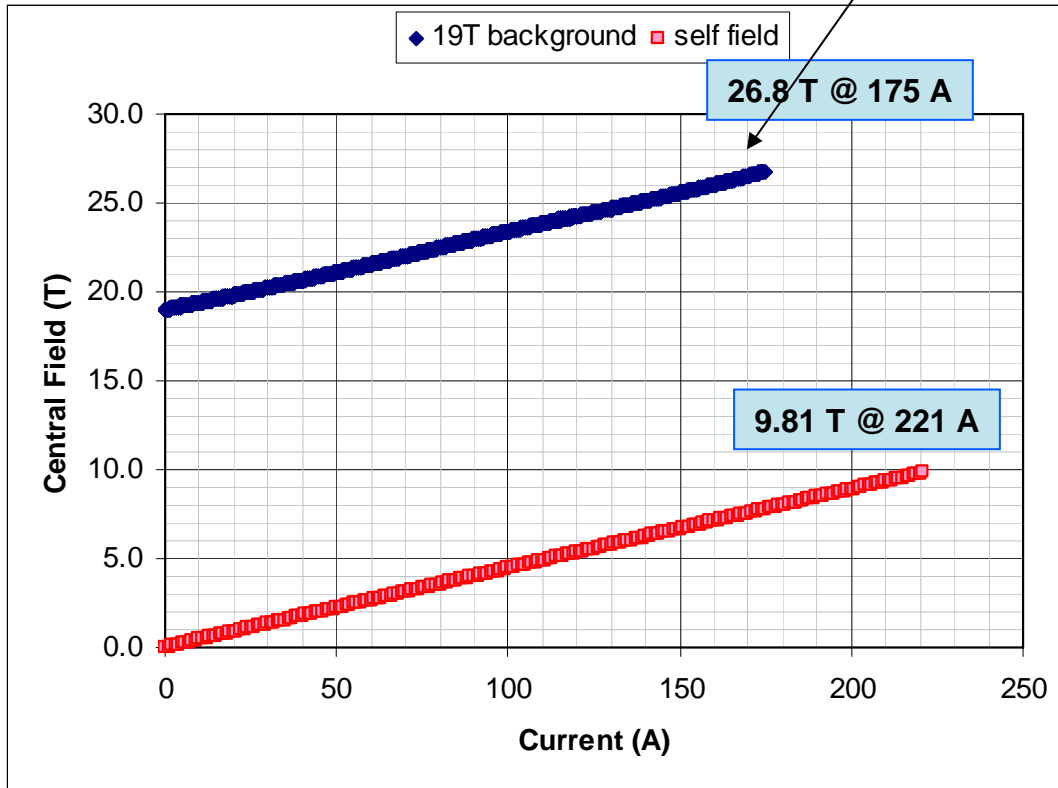


<b>Coil ID</b>	<b>9.5 mm (clear)</b>
<b>Winding ID</b>	<b>19.1 mm</b>
<b>Winding OD</b>	<b>~ 87 mm</b>
<b>Coil Height</b>	<b>~ 51.6 mm</b>
<b># of Pancakes</b>	<b>12 (6 x double)</b>
<b>2G tape used</b>	<b>~ 462 m</b>
<b>Average <math>I_c</math> of tapes in coil</b>	<b>78 A in 4 mm width (77 K, self field)</b>
<b># of turns</b>	<b>~ 2772</b>
<b>Coil <math>J_e</math></b>	<b>~1.569 A/mm<sup>2</sup> per A</b>
<b>Coil constant</b>	<b>~ 44.46 mT/A</b>

Coil tested by H. Weijers, D. Markewicz, & D. Larbalestier, NHMFL, FSU

# High field insert coil achieves world records for highest HTS field, highest magnetic field by a SC magnet

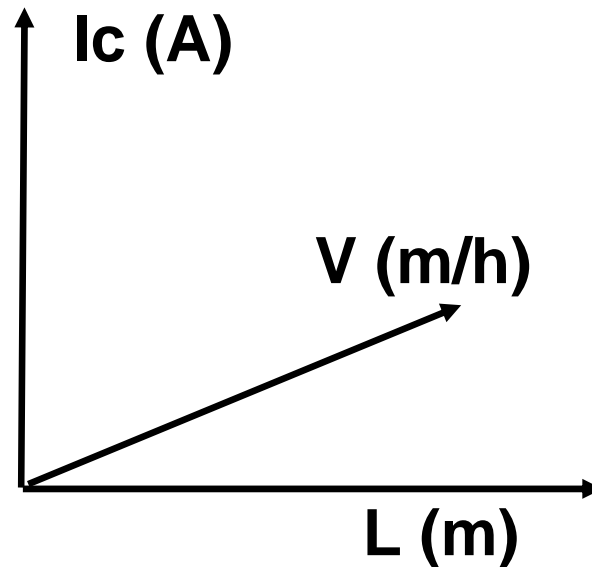
**Peak hoop stress ~ 215 MPa, well below tape limit**



Ic of Tapes in Coil	72 A – 82 A (77K, sf)
4.2 K Coil Ic - self field	221 A
4.2 K Amp Turns @ Ic-self field	612,612
4.2 K Je @ Ic, self field	346.7 A/mm <sup>2</sup>
4.2K Peak Radial Field @ Ic, self field	3.2 T
4.2 K Central field – self field	<b>9.81 T</b>
4.2 K Coil Ic – 19 T background (axial)	175 A
4.2 K Amp Turns @ Ic – 19 T background (axial)	485,100
4.2 K Je @ Ic, 19 T background (axial)	274.6 A/mm <sup>2</sup>
4.2 K Peak Radial Field @ Ic, 19 T bkgd (axial)	2.7 T
4.2K Central Field – 19 T background (axial)	<b>26.8 T</b>

# Key metrics of 2G wire for broad market penetration

- Key metrics determining the price-performance characteristics of 2G HTS wire and qualifying for applications:
  - $I_c$       500 A/cm at 0T & 77K
  - $I_c(B)$     100 A/cm at 1.5T & 77K
  - $L$         1 km
  - $V$         1000 km/year



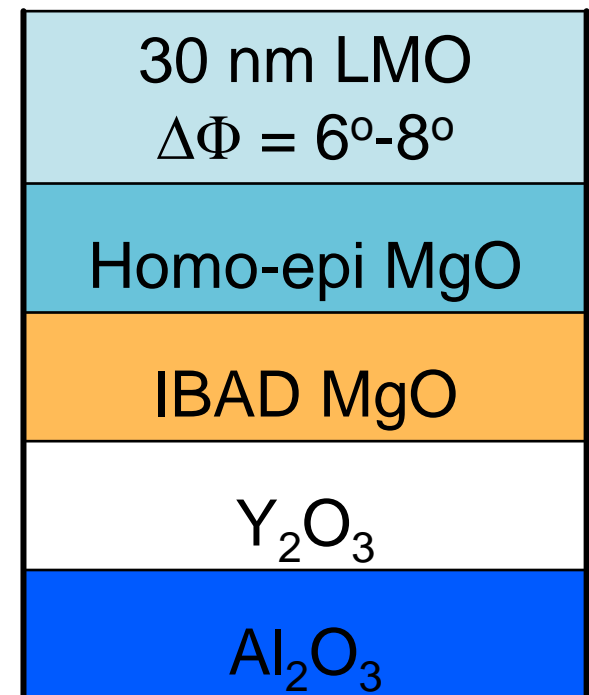
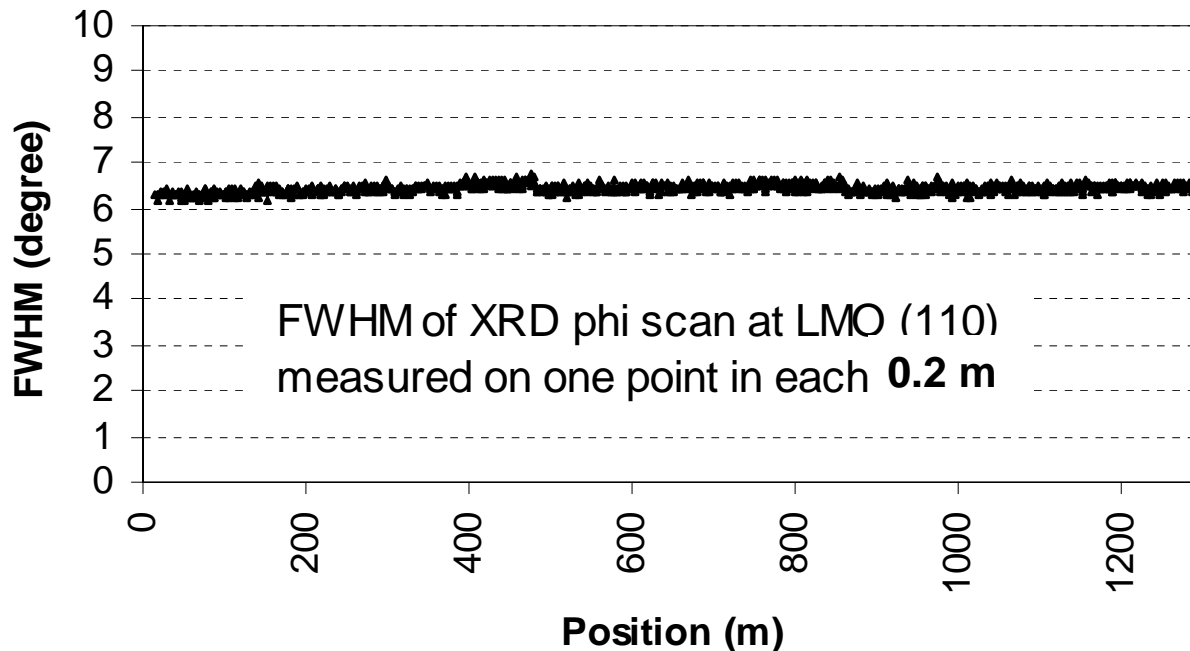
SuperPower's 2G wire technology is based on high throughput processes

Process	Throughput of 4mm wide tape (m/h)
<b>MOCVD</b>	<b>180 (for ~ 1 <math>\mu\text{m}</math> HTS layer)</b>
<b>Homo-epi MgO + LMO</b>	<b>345</b>
<b>IBAD MgO</b>	<b>360</b>
<b>Alumina + Yttria</b>	<b>750</b>

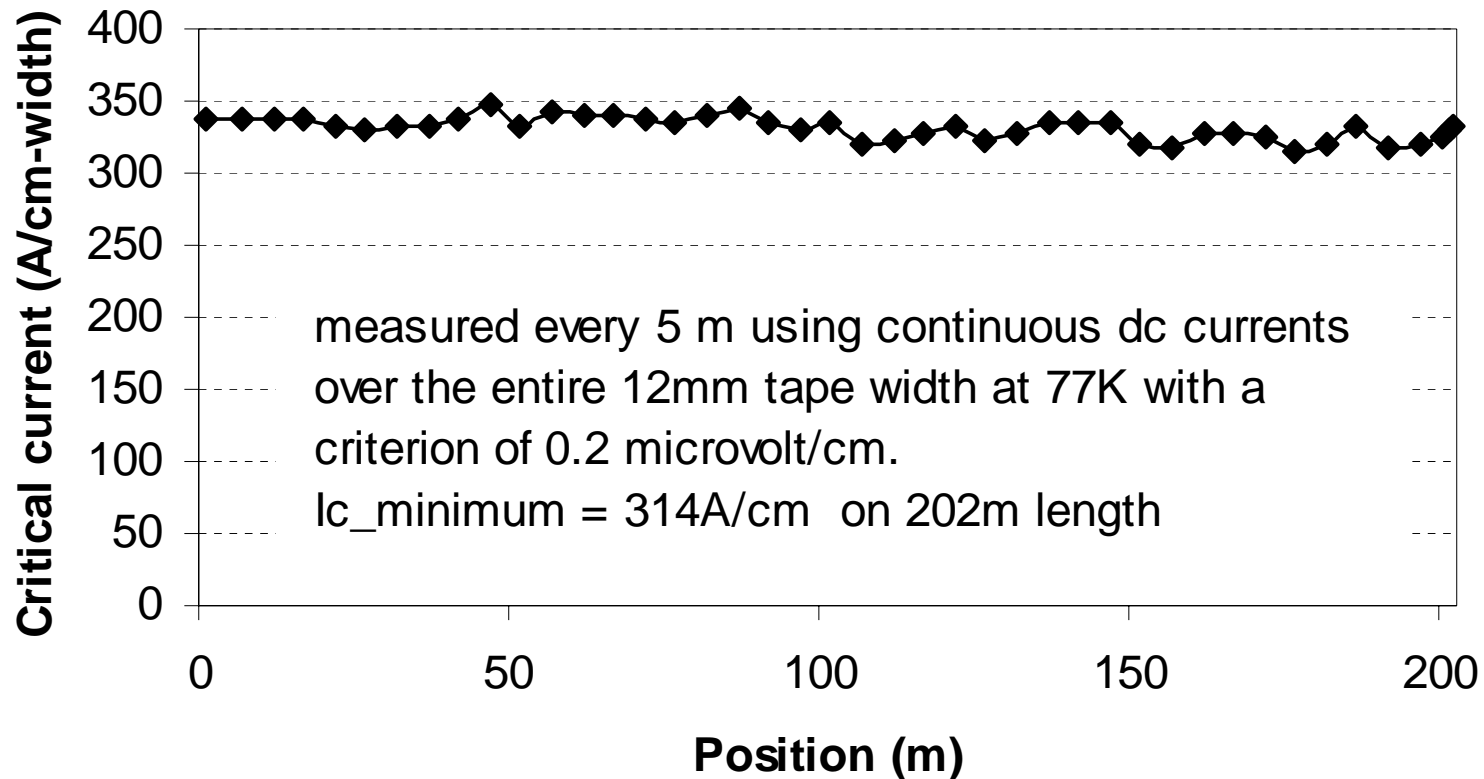


# Excellent in-plane alignment has been uniformly distributed on 1.3 km+ lengths

The FWHM values of the phi-scan at (110) of LMO, the cap layer of the 5-layer buffer stack, typically range from 6 to 8 degrees for the km+ lengths

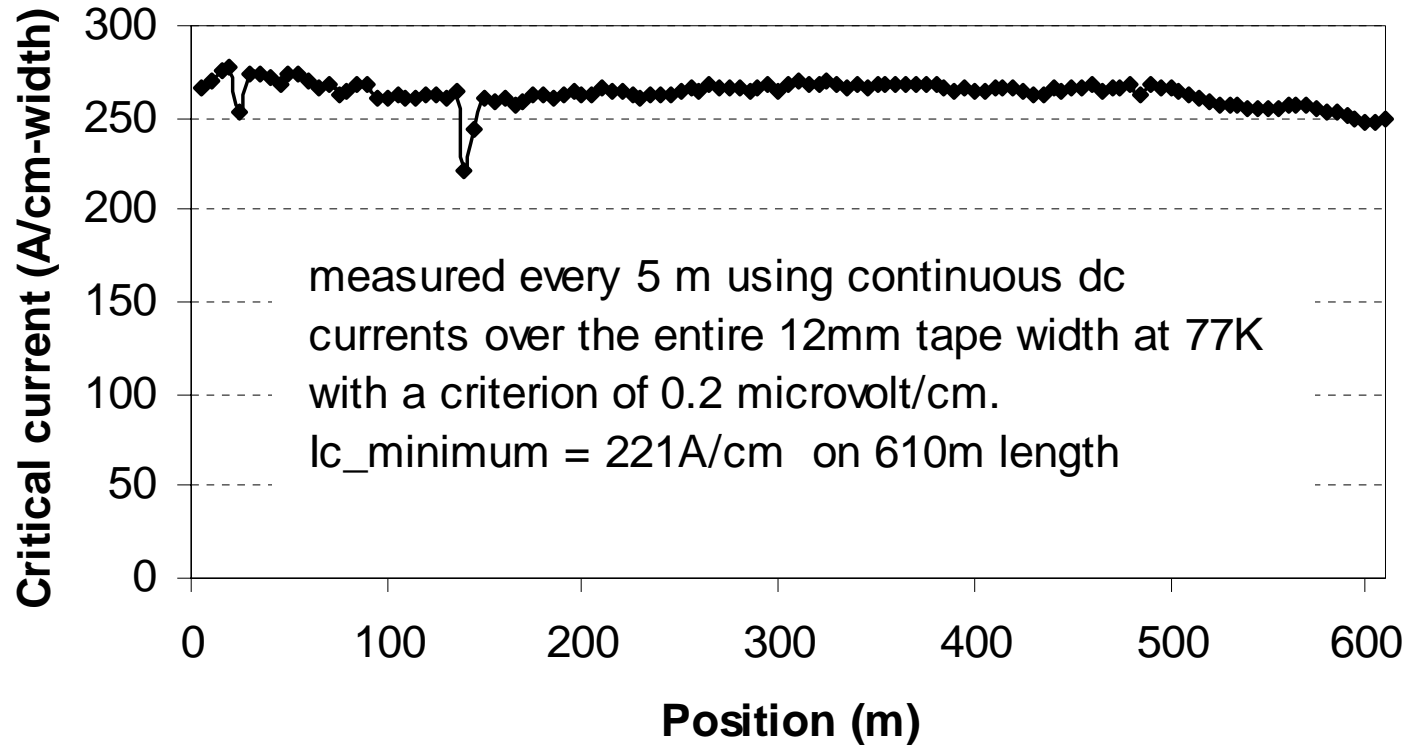


# High critical currents in long lengths processed at high speeds



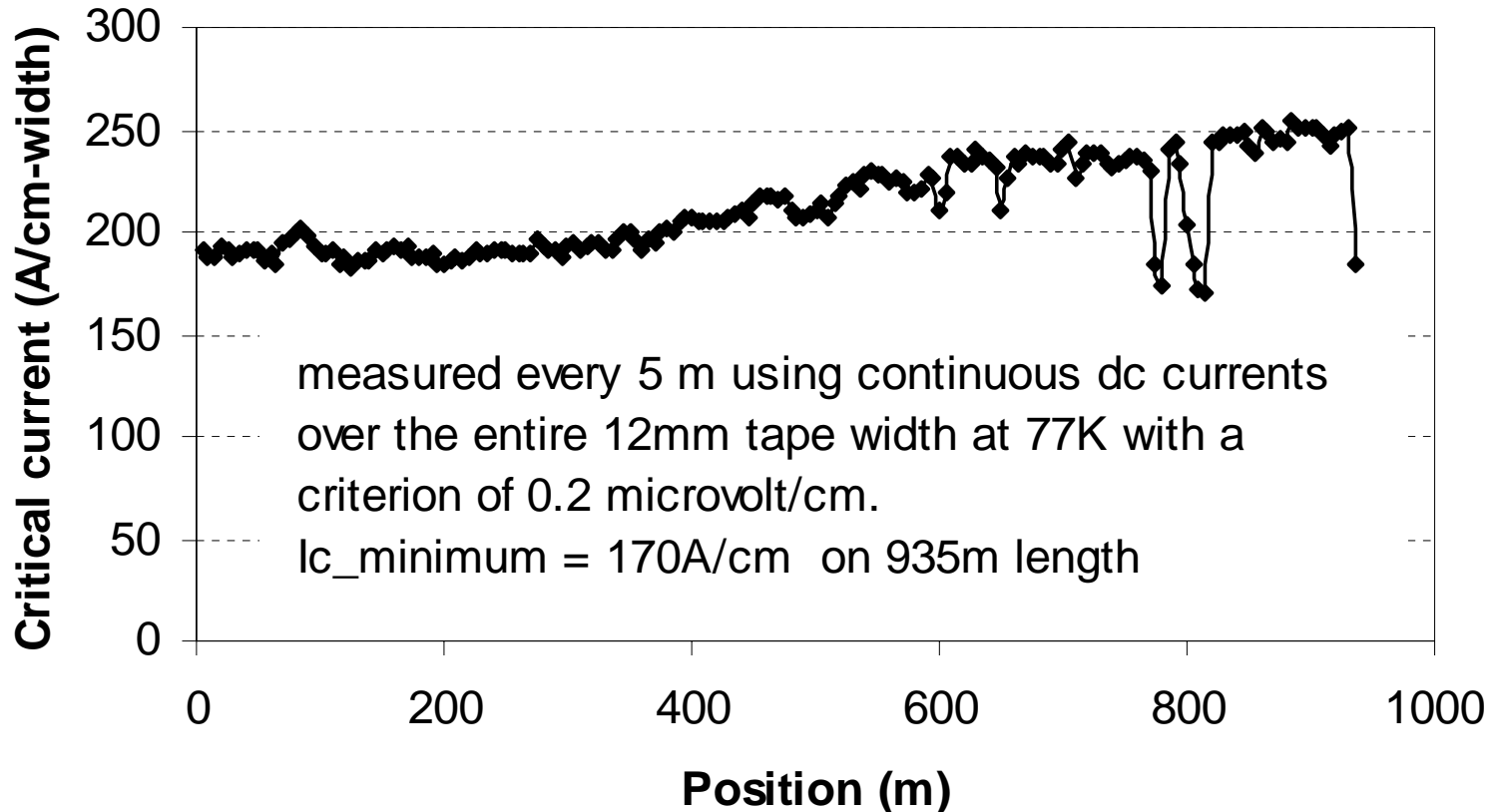
- Minimum Ic = 314 A/cm over 202 m
- processed with MOCVD throughput of 90m/h
- Uniformity over 202 m = 2.4%

# High critical currents in long lengths processed at high speeds



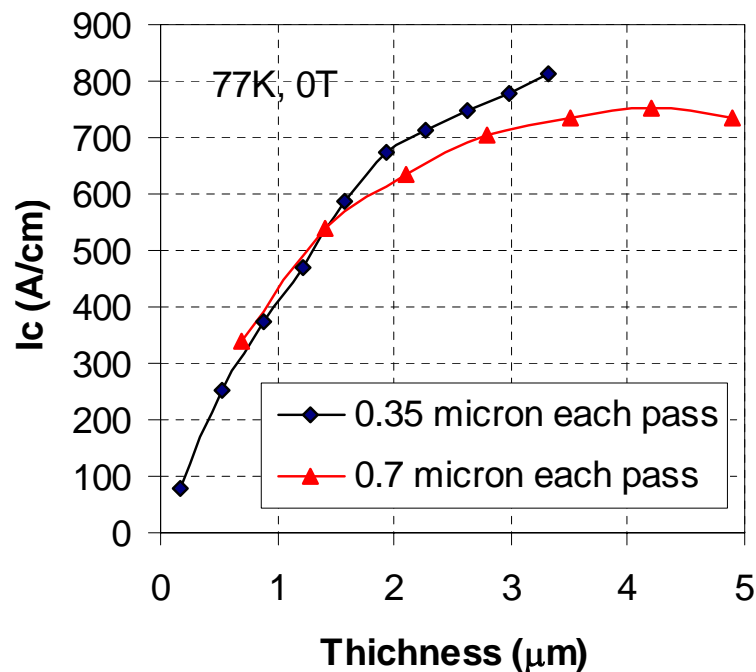
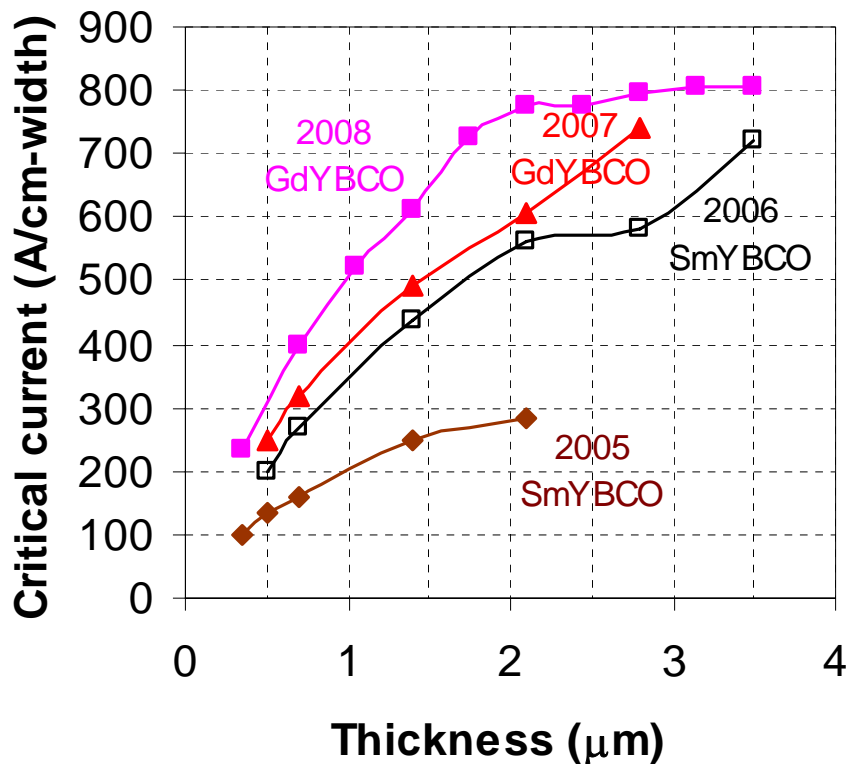
- Minimum Ic = 221 A/cm over 610 m
- Processed with MOCVD throughput of 90m/h
- Uniformity over 610 m = 2.65%

# High critical currents in long lengths processed at high speeds



- Minimum Ic = 170 A/cm over 935 m
- Processed with MOCVD throughput of 135m/h
- $I_c \times L = 158,950\text{m}$

# Capability of 320 A achieved in 4 mm widths



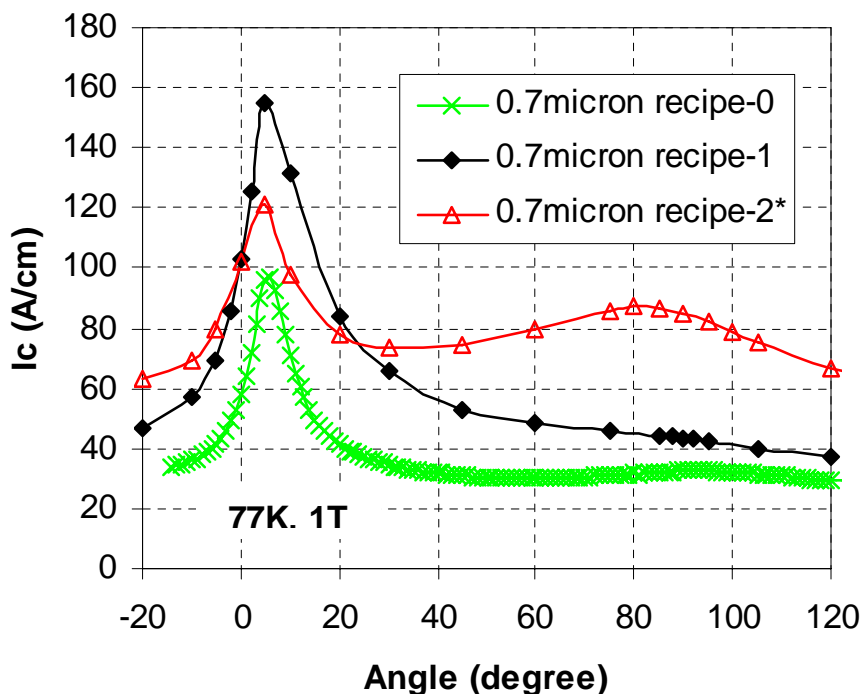
Over 1.2 m length  
 $I_c = 964 \text{ A} = 803 \text{ A/cm}$

Over 1 m length  
 $I_c = 976 \text{ A} = 813 \text{ A/cm}$

2.1 μm film made in 6 passes:  $I_c = 929 \text{ A} = 774 \text{ A/cm}$  ( $J_c = 3.68 \text{ MA/cm}^2$ )

3.3 μm film made in 10 passes:  $I_c = 976 \text{ A} = 813 \text{ A/cm}$  ( $J_c = 2.44 \text{ MA/cm}^2$ )

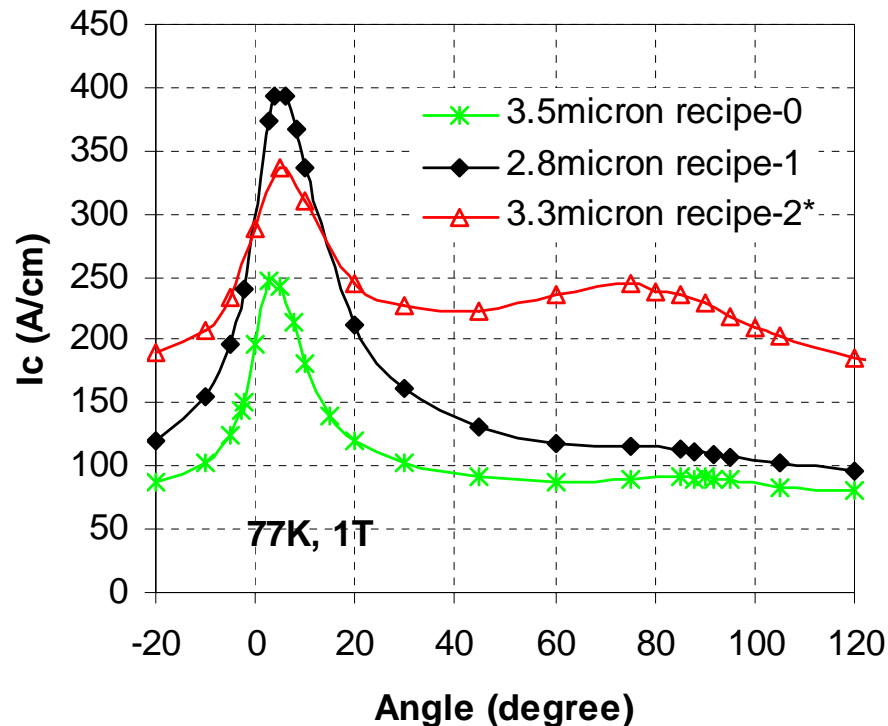
# Dramatic improvements achieved in in-field performance of SuperPower 2G wire



**For 0.7micron recipe-2\***

**Recipe-1: strong pinning for B//ab**

**Recipe-2\*: strong pinning for B//c**



**For 3.3micron film of recipe-2\***

**Ic\_minimum(77K, 1T) = 185.6A/cm**

**Ic\_minimum(65K, 3T) = 267.3A/cm**

**Ic(77K, B//c=3T) = 71.8A/cm**

**Best in-field performance of all commercial 2G wire**

# Summary

- Prototype applications including cable and high field coil with SuperPower's 2G wire demonstrated the viability for commercialization.
- SuperPower's 2G technology development is focused on three key metrics for a broad market penetration and improvement has been made on all areas.
  - High throughput:
    - 750m/h for sputtering Al<sub>2</sub>O<sub>3</sub>+Y<sub>2</sub>O<sub>3</sub> base layer
    - 360m/h for IBAD MgO template
    - 345m/h for sputtering Homo-epi MgO+LMO buffer
    - 180m/h for MOCVD REBCO
  - High I<sub>c</sub>:
    - 813A/cm-width at 77K and self-field over 1 meter length
  - Long lengths:
    - 314A/cm-width over 202m
    - 221A/cm-width over 610m
    - 170A/cm-width over 935m
- Superior mechanical properties and in-field performance make 2G HTS wires suitable for high field and high stress applications

Questions?

Thank you for your interest!

For further information about SuperPower,  
please visit us at: [www.superpower-inc.com](http://www.superpower-inc.com)  
or e-mail: [info@superpower-inc.com](mailto:info@superpower-inc.com)